



Ultrahigh-Speed Switching Applications

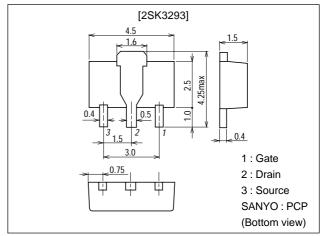
Features

- · Low ON resistance.
- · Ultrahigh-speed switching.
- · 4V drive.

Package Dimensions

unit:mm

2062A



Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$

| Parameter | Symbol | Conditions | Ratings | Unit |
|-----------------------------|------------------|--|-------------|------|
| Drain-to-Source Voltage | V _{DSS} | | 60 | V |
| Gate-to-Source Voltage | V _{GSS} | | ±20 | V |
| Drain Current (DC) | ID | | 3 | Α |
| Drain Current (Pulse) | I _{DP} | PW≤10μs, duty cycle≤1% | 12 | Α |
| Allowable Power Dissipation | P _D | Mounted on a ceramic board (250mm ² ×0.8mm) | 1.5 | W |
| | ٠ b | Tc=25°C | 3.5 | W |
| Channel Temperature | Tch | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Electrical Characteristics at Ta = 25°C

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|--|-----------------------|--|---------|-----|-----|-------|
| | | | min | typ | max | 01111 |
| Drain-to-Source Breakdown Voltage | V(BR)DSS | I _D =1mA, V _{GS} =0 | 60 | | | V |
| Zero Gate Voltage Drain Current | IDSS | V _{DS} =60V, V _{GS} =0 | | | 10 | μΑ |
| Gate-to-Source Leakage Current | IGSS | V_{GS} =±16V, V_{DS} =0 | | | ±10 | μΑ |
| Cutoff Voltage | V _{GS} (off) | V_{DS} =10V, I_D =1mA | 1.0 | | 2.4 | V |
| Forward Transfer Admittance | yfs | V _{DS} =10V, I _D =1.5A | 2.6 | 3.6 | | S |
| Static Drain-to-Source On-State Resistance | R _{DS} (on)1 | I _D =1.5A, V _{GS} =10V | | 115 | 150 | mΩ |
| | R _{DS} (on)2 | I _D =1A, V _{GS} =4V | | 150 | 210 | mΩ |

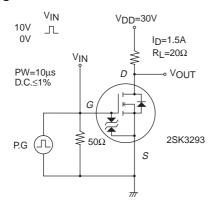
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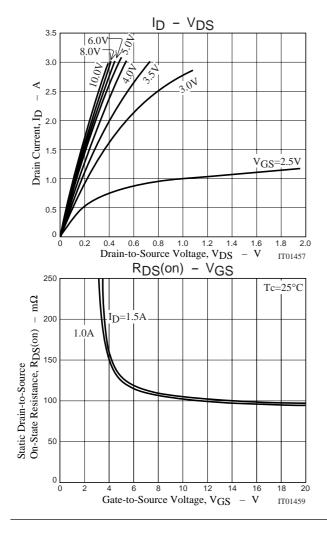
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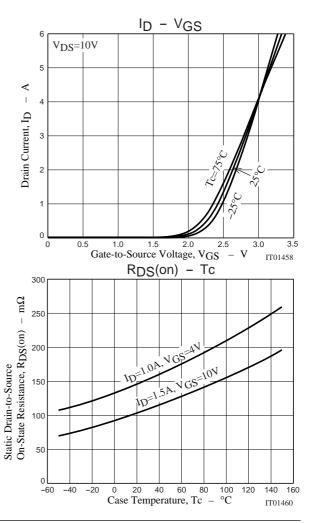
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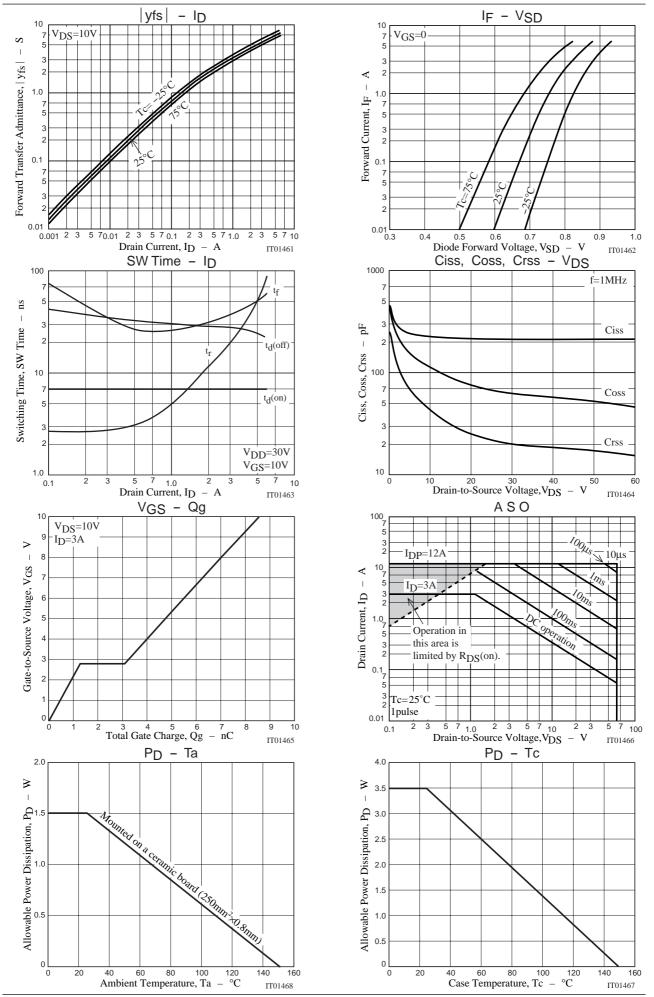
| Parameter | Symbol | Conditions | Ratings | | | Unit |
|-------------------------------|---------------------|--|---------|------|-----|------|
| | | | min | typ | max | Oill |
| Input Capacitance | Ciss | V _{DS} =20V, f=1MHz | | 220 | | pF |
| Output Capacitance | Coss | V _{DS} =20V, f=1MHz | | 75 | | pF |
| Reverse Transfer Capacitance | Crss | V _{DS} =20V, f=1MHz | | 25 | | pF |
| Turn-ON Delay Time | t _d (on) | See specified Test Circuit | | 7 | | ns |
| Rise Time | t _r | See specified Test Circuit | | 8 | | ns |
| Turn-OFF Delay Time | td(off) | See specified Test Circuit | | 30 | | ns |
| Fall Time | t _f | See specified Test Circuit | | 29 | | ns |
| Total Gate Charge | Qg | V _{DS} =10V, V _{GS} =10V, I _D =3A | | 8.6 | | nC |
| Gate-to-Source Charge | Qgs | | | 1.3 | | nC |
| Gate-to-Drain "Miller" Charge | Qgd | | | 1.8 | | nC |
| Diode Forward Voltage | V _{SD} | I _S =3A, V _{GS} =0 | | 0.83 | 1.2 | V |

Switching Time Test Circuit









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